

Colossal dielectric constant and Maxwell-Wagner relaxation in $\text{Pb}(\text{Fe}_{1/2}\text{Nb}_{1/2})\text{O}_3\text{-}x\text{PbTiO}_3$ single crystals

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Frequency, temperature and voltage dependent dielectric properties of $\text{Pb}(\text{Fe}_{1/2}\text{Nb}_{1/2})\text{O}_3\text{-}x\text{PbTiO}_3$ single crystals were studied and colossal dielectric constant ($\epsilon > 10^5$) behavior was first observed in a broad frequency and temperature range. The colossal dielectric constant behavior is attributed to Maxwell-Wagner effect and is simulated by an equivalent circuit with two parallel RC elements. The relaxor-like behavior which covers a broad temperature range ($\sim 150\text{K}$) is supposed to be MW relaxation. The activation energies of the samples ($x = 0.07, 0.48$) are calculated to be 0.158 eV and 0.169 eV respectively. Two different extrinsic electrical responses were identified by voltage dependent dielectric constant curves.

Recently, materials exhibiting colossal dielectric constant (CDC) have attracted significant attention because of their high dielectric constant and potential applications in electronic devices, such as high dielectric capacitors, capacitor sensors, random access memories and so on.[1] The common feature of CDC materials is that they have extremely high dielectric constant ($10^3 \sim 10^5$) at room temperature, and weakly frequency and temperature dependent. A variety of materials have been reported to exhibit CDC behavior, including magnetic, nonferroelectric and ferroelectric materials such as $\text{CaCu}_3\text{Ti}_4\text{O}_{12}$, $\text{Pr}_{0.6}\text{Ca}_{0.4}\text{MnO}_3$ and $\text{BaZr}_{0.1}\text{Ti}_{0.9}\text{O}_3$ etc. It has been generally accepted that most of the CDC behavior is not due to the intrinsic materials but from extrinsic effect which is due to Maxwell-Wagner (MW) effect.[2, 4, 6] MW polarization can arise from internal interfacial boundary layers and external depletion layers at the interface of electrode /sample surface because of Schottky barrier effect. Both internal and external layers can be recognized as extrinsic electrical response, while the electrical response from the bulk sample can be recognized as intrinsic electrical response.[3]

The physical mechanism can be interpreted as follows. Our samples are slightly conductive due to oxygen vacancy and electron hopping between Fe^{3+} and Fe^{2+} , which leads to a depletion layer formed at the electrode/sample surface due to Schottky barrier effect. The depletion layer can be equivalent to a large resistance and a large capacitance, which is in series with bulk sample with much smaller resistance and capacitance. The characteristic frequency of the RC element can be described as $f=1/2RC$. So, characteristic frequency of bulk sample is much higher than that of depletion layer. At high frequencies ($f \gg 10^5$), response from depletion layer can not follow the applied ac field, so only the bulk response is measured, which corresponds to much lower dielectric constant.

At low frequencies, depletion layer response is able

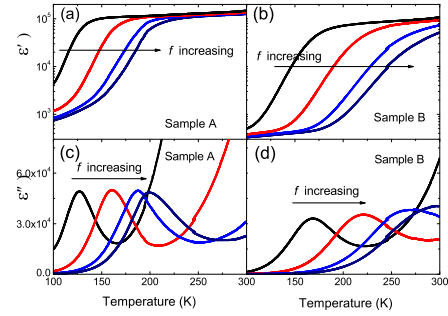


FIG. 1: curves of both samples with Al and Au electrodes respectively. It can be seen clearly that dielectric spectra of both samples changed significantly. First, dielectric constants of both samples are considerably enhanced when Au electrode is used.

to follow the applied ac field, and the field is dropped greatly on the depletion layer because of its large resistance. Then the contact response is measured, which causes CDC behavior. From Fig.1 we can see that $\epsilon' - F$ and $\epsilon'' - F$ curves of the two samples are very different. First, step-frequency of sample A is about 105 Hz, which is higher than that of sample B (~ 104 Hz). Second, dielectric constant and loss of sample A at low frequency plateau are bigger than that of sample B. This is because that there are fewer Fe ions in sample B with more Pb-TiO_3 doped into PFN, which leads to lower charge carrier concentration. So sample B has bigger resistivity than sample A, which results in lower characteristic frequency and smaller dielectric loss. The capacitance of depletion layer per unit area can be expressed as follows.[5]

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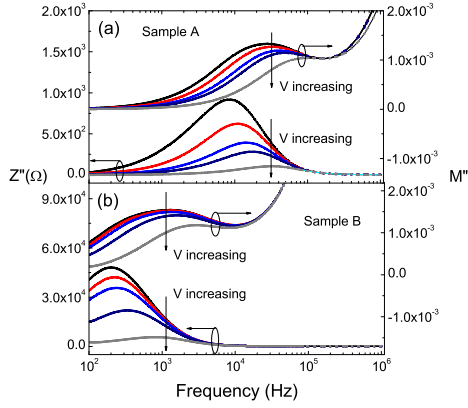


FIG. 2: Frequency-dependent imaginary part of impedance for sample A (a) and sample B (b) under different dc bias voltages.

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